UNISONIC TECHNOLOGIES CO., LTD

UTG7N65-S

Preliminary

Insulated Gate Bipolar Transistor

650V TRENCH GATE FIELD-STOP IGBT

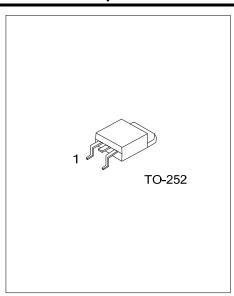
DESCRIPTION

The UTC **UTG7N65-S** is an Trench Field-Stop Insulated Gate Bipolar Transistor. it uses UTC's advanced technology to provide customers with high switching speed, low saturation voltage and low switching loss, etc.

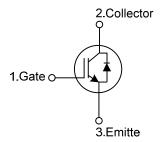
The UTC ${\it UTG7N65-S}$ is suitable for the resonant or soft switching applications.

■ FEATURES

- * High switching speed
- * High avalanche ruggedness
- * Low saturation voltage: V_{CE(SAT).Typ.}=1.5V @ I_C=7.0A, V_{GE}=15V (T_C =25°C)



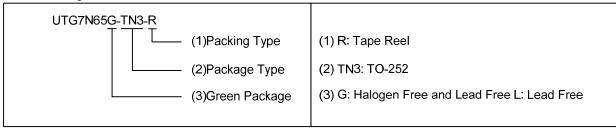
■ SYMBOL



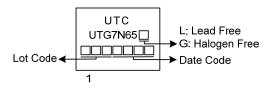
ORDERING INFORMATION

Ordering Number		Daalaana	Pin Assignment			Da aldin n	
Lead Free	Halogen Free	Package	1	2	3	Packing	
UTG7N65L-TN3-R	UTG7N65G-TN3-R	TO-252	G	С	E	Tape Reel	

Note: Pin Assignment: G: Gate C: Collector E: Emitter



MARKING



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ABSOLUTE MAXIMUM RATINGS

PARAMETER		SYMBOL	RATINGS	UNIT
Collector-Emitter Voltage		V _{CES}	650	V
Gate-Emitter Voltage		\/	±20	V
Transient Gate-emitter voltage (tp < 5 ms)		V_{GES}	±25	V
Cantinua Callantar Cumant	T _C =25°C		14	Α
Continuous Collector Current	T _C =100°C	Ic	7	Α
Collector Current Pulsed (Note 1)		I _{CM}	28	Α
Diode Forward Current	T _C =25°C	l _F	14	Α
	T _C =100°C		7	Α
Short Circuit Withstand Time $V_{\text{GE}} = 15\text{V}, \ V_{\text{CC}} \le 200\text{V}$ Allowed number of short circuits < 1000 Time between short circuits: $\ge 1.0\text{s}$ $T_{\text{VJ}} = 25^{\circ}\text{C}$		tsc		μs
			3	
Power Dissipation (T _C =25°C)		P _D	40	W
Operating Junction Temperature		T_J	-40 ~ +175	°C
Storage Temperature Range		T _{STG}	-55 ~ +175	°C

Notes: 1. Absolute maximum ratings are stress ratings only and functional device operation is not implied. Absolute maximum ratings are those values beyond which the device could be permanently damaged.

■ THERMAL DATA

PARAMETER	SYMBOL	RATINGS	UNIT
Junction to Case	θлс	3.125	°C/W

^{2.} Pulse width limited by maximum junction temperature.

ELECTRICAL CHARACTERISTICS (Tc=25°C, unless otherwise noted)

			1	1				
PARAMETER	SYMBOL	TEST CONDITIONS		MIN	TYP	MAX	UNIT	
Off Characteristics		<u> </u>						
Collector-Emitter Breakdown Voltage	BV _{CES}			650			V	
Collector Cut-Off Current	I _{CES}	V _{CE} =650V, V _{GE} =0V				5	μΑ	
G-E Leakage Current	Iges	V _{CE} =0V, V _{GE} =±20V				±100	nA	
On Characteristics								
Gate to Emitter Threshold Voltage	$V_{GE(TH)}$	Ic=250μA, VcE=VGE		4.0		6.5	٧	
Calle star to Engitter Caturation Valtage	V	Ic=7.0A, V _{GE} =15V	c=25°C		1.5	2.1	V	
Collector to Emitter Saturation Voltage	V _{CE(SAT)}	TC=7.0A, VGE=15V	c=125°C		1.9		V	
Dynamic Characteristics		_						
Input Capacitance	CIES	V _{CE} =25V, V _{GE} =0V, f=1MHz			694		pF	
Output Capacitance	Coes				41.2		pF	
Reverse Transfer Capacitance	Cres				12.5		pF	
Switching Characteristics								
Total Gate Charge	Q_{G}	V _{CE} =520V, I _C =7.0A, V _{GE} =15V			53.7		nC	
Gate-Emitter Charge	Q_{GE}				15		nC	
Gate-Collector Charge	Q _{GC}				23.9		nC	
Turn-On Delay Time	t _{DON)}	Vcc=650V, Ic=7.0A, R _G =5Ω, V _{GE} =0~15V, L=1000μH			16.9		ns	
Rise Time	t _R				27.5		ns	
Turn-Off Delay Time	t _{DOFF)}				73.5		ns	
Fall Time	t⊧				209		ns	
Turn-On Switching Loss	Eon				0.254		mJ	
Turn-Off Switching Loss	Eoff				0.226		mJ	
SOURCE- DRAIN DIODE RATINGS AN	D CHARACTE	ERISTICS						
Forward Voltage Drop	VF	I _F =7.0A			1.67	3.0	V	
Reverse Recovery Time	t _{rr}	I _F =7.0A, dI/dt=100A/μS,			43.3		ns	
Reverse Recovery Charge	Qrr	V _{CC} =400V			10.6		nC	

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